

P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
-20V	$90m\Omega @V_{GS} = -4.5V$	-2.5A
-20V	120mΩ @V _{GS} = -2.5V	-2.0A

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Motor Control
- Power Management Functions
- Backlighting

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

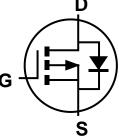
Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)

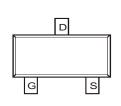












Top View

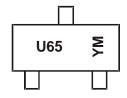
Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2165UW-7	SOT323	3000/Tape & Reel
DMP2165UW-13	SOT323	10000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



U65 = Product Type Marking Code YM or \overline{Y} M = Date Code Marking for SAT Y or \overline{Y} = Year (ex: F = 2018) M = Month (ex: 9 = September)

Date Code Key

Year	20)17	2018	2019	202	20	2021	2022	2023	2	024	2025
Code		E	F	G	Н			J	K		L	М
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V_{DSS}	-20	V
Gate-Source Voltage		V_{GSS}	±12	V
Continuous Drain Current (Note 6) V _{GS} = -4.5V	I _D	-2.5 -2.0	А	
Maximum Continuous Body Diode Forward Current	(Note 6)	I _S	-1.0	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	6) (Note 6)	I _{DM}	-15	Α

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		P_{D}	0.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	259	°C/W
Total Power Dissipation (Note 6)		P_{D}	0.7	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	175	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

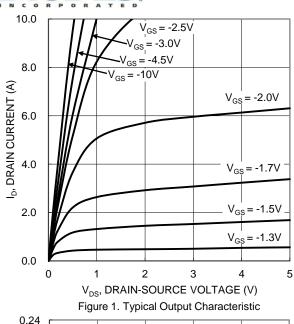
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

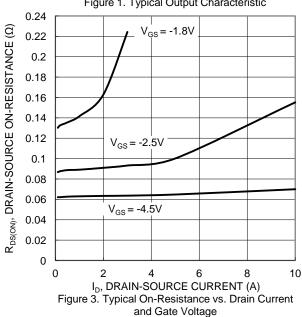
Characteristic	Cumbal	Min	Time	Max	Unit	Toot Condition
OFF CHARACTERISTICS (Note 7)	Symbol	IVIII	Тур	IVIAX	Unit	Test Condition
	D) (20		l	17	lv
Drain-Source Breakdown Voltage	BV _{DSS}	-20			V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}			-1.0	μA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage	IGSS		—	±100	nA	$V_{GS} = \pm 12V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	-0.4		-1.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
			63	90		$V_{GS} = -4.5V, I_D = -1.5A$
Static Drain-Source On-Resistance	R _{DS(ON)}	_	83	120	mΩ	$V_{GS} = -2.5V$, $I_D = -1.2A$
			160	180		$V_{GS} = -1.8V$, $I_{D} = -1.2A$
Diode Forward Voltage	V_{SD}	_	-0.7	-1.1	V	$V_{GS} = 0V, I_{S} = -1A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C _{iss}	_	335		pF	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
Output Capacitance	Coss	_	72		pF	$V_{DS} = -15V, V_{GS} = 0V$ - f = 1.0MHz
Reverse Transfer Capacitance	C_{rss}	_	32	_	pF	1 – 1.00112
Gate Resistance	R_{G}	_	15.5	_	Ω	$V_{GS} = 0V, V_{DS} = 0V, f = 1.0MHz$
Total Gate Charge	Qg	_	3.5	_	nC	V 4.5V.V 4V
Gate-Source Charge	Q_{gs}	_	0.4	_	nC	$V_{GS} = -4.5V$, $V_{DS} = -4V$, $-I_{D} = -3.5A$
Gate-Drain Charge	Q_{gd}	_	1.1	_	nC	ID = -3.5A
Turn-On Delay Time	t _{D(ON)}	_	3.7	_	ns	
Turn-On Rise Time	t _R	_	8.7	_	ns	$V_{DS} = -4V$, $V_{GS} = -4.5V$,
Turn-Off Delay Time	t _{D(OFF)}	_	17.8	_	ns	$R_G = 6\Omega$, $I_D = -1A$
Turn-Off Fall Time	t _F	_	8	_	ns	
Reverse Recovery Time	t _{RR}	_	9	_	ns	$I_F = -4A$, di/dt = 100A/ μ s
Reverse Recovery Charge	Q_{RR}		1.5	_	nC	$I_F = -4A$, $di/dt = 100A/\mu s$

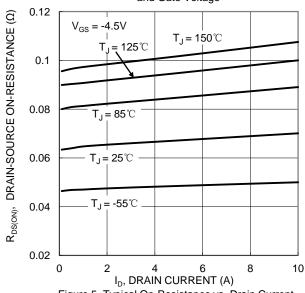
Notes:

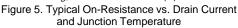
- 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.
- 6. Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to product testing.

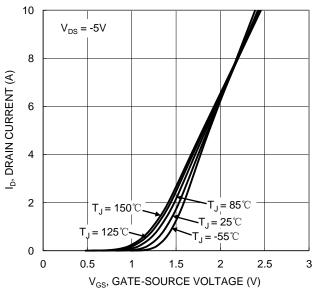
DMP2165UW



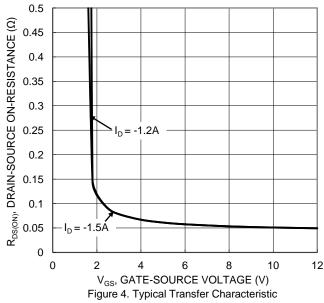








V_{GS}, GATE-SOURCE VOLTAGE (V)
Figure 2. Typical Transfer Characteristic



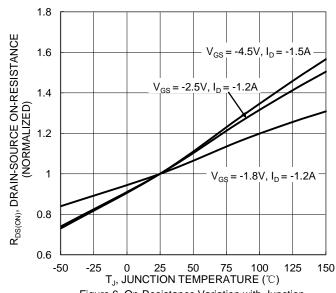
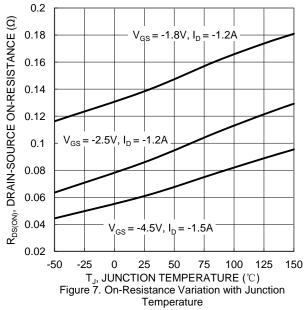
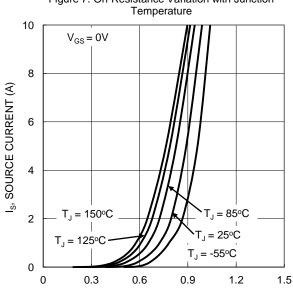


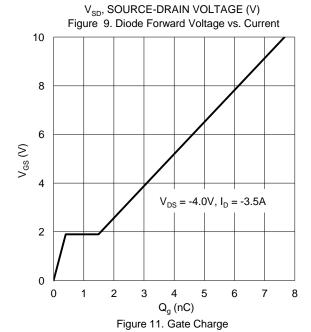
Figure 6. On-Resistance Variation with Junction Temperature

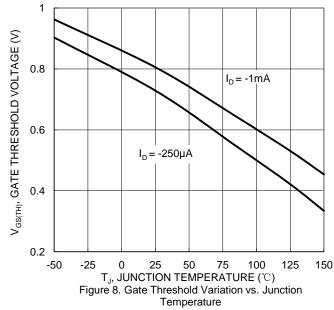


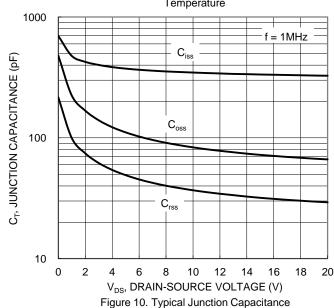


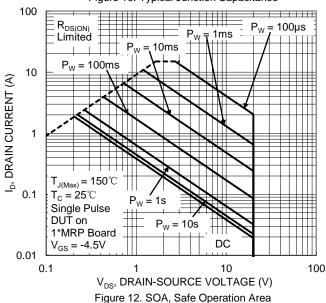














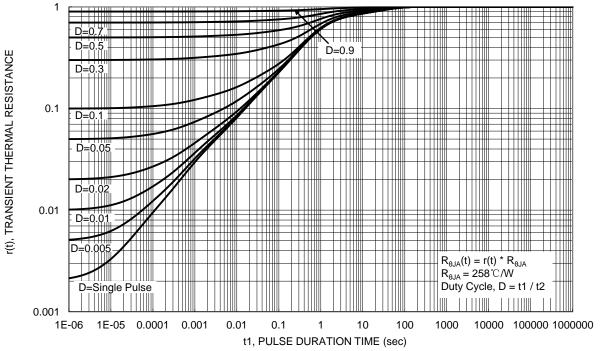


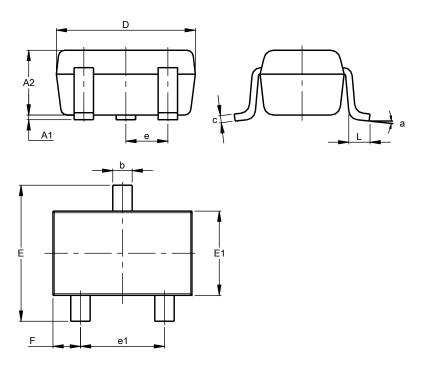
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323

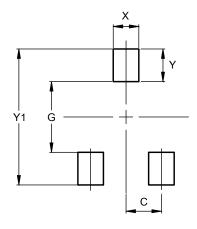


SOT323						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.90	1.00	0.95			
b	0.25	0.40	0.30			
С	0.10	0.18	0.11			
D	1.80	2.20	2.15			
Е	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
е	C).650 B	SC			
e1	1.20	1.40	1.30			
F	0.375 0.475 0.425					
L	0.25	0.40	0.30			
а	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323



Dimensions	Value (in mm)		
С	0.650		
G	1.300		
Х	0.470		
Y	0.600		
Y1	2 500		



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